# Im aginary chem ical potential quantum M onte C arlo for H ubbard m olecules 

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#### Abstract

W e generalize the im aginary chem ical potential quantum M onte C arlo (Q M C ) m ethod proposed by D agotto et al. Phys. Rev. B 41, R 811 (1990)] to system s w thout particle-hole sym m etry. The generalized $m$ ethod is tested by com paring the results of the Q M C sim ulations and exact diagonalization on $s m$ all $H$ ubbard $m$ olecules, such as tetrahedron and truncated tetrahedron. R esults of the application of the $m$ ethod to the $\mathrm{C}_{60} \mathrm{H}$ ubbard m olecule are discussed.


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## I. INTRODUCTION

K now ledge of the evolution of energy levels w ith doping in strongly correlated system $s$ is of signi cant im portance for understanding the physicalm echanism $s$ leading to their unconventional properties. For exam ple, infor$m$ ation about the changes in the ground state energy of m odel electron system $s$ (such as Hubbard model) upon electron or hole doping $m$ ay be used to con $m$ or disprove hypotheses about the origin of the pairing $m$ echanism, eventually leading to superconductivity. A s accessing this inform ation analytically usually requires the use of various approxim ations, num erical techniques are often the only tools which can provide unbiased estim ates for the observables of interest.

W e have recently applied the auxiliary eld quantum M onte Carlo (AFQMC) on a C 60 molecule to extract the electronic binding energies [1] [1]. AFQM C has been widely used in H ubbard H am iltonian sim ulations since its introduction by $B$ lankenbecler et al. [2,
 Being a nite-tem perature technique, AFQMC does not allow easy access to the physical observables, not represented by therm odynam ic averages, such as energy gaps. A convenient procedure to extract this additional infor$m$ ation_from the AFQM C data was proposed by D agotto et al. [G] $]$, who introduced im aginary chem ical potentials in AFQMC simulations. It was then used to extract the charge gaps of the one-band $H$ ubbard $m$ odel on nite two-dim ensional (2D ) square lattioes.

In the present paper we generalize this form alism to system s without particle-hole symmetry, such as the tetrahedron, truncated tetrahedron and $\mathrm{C}_{60} \mathrm{~m}$ olecules. $T$ he canonicalpartition function ratios are obtained from the expansions of the AFQMC determ inant ratios for a set of nite tem peratures $T$, which are subsequently used to extract charge gaps at low tem peratures. T his generalization results in the appearance of an extra phase factor in the expansion of the determ inant ratios, which reduces to unity in the particle-hole sym $m$ etric system $s$.
$T$ he rest of the paper is organized as follow s. First, we brie y describe the im aginary chem ical potential QMC (ICPQMC) form alism. Then simulation results on som e Hubbard molecules are presented to illustrate
ourm ethod. The results are com pared with the data obtained by exact diagonalization (ED) on sm allm olecules and projector QMC (PQMC) on larger ones.

## II. METHODOLOGY

W e start w ith an expansion ofthe grand canonicalpartition function $Z_{G C}()$ in term $s$ of canonical partition functions $Z_{C}(n)\left[{ }_{6}^{6}\right]:$

$$
\begin{equation*}
Z_{G C}()=\operatorname{Tre}(\hat{H} \quad \hat{N})=e^{N} \hat{N}^{\hat{N}} e^{n} Z_{C}(n) ; \tag{1}
\end{equation*}
$$

where $=1=\left(k_{B} T\right)$ is the inverse tem perature, is the chem icalpotential, $n$ is the deviation of the particle num ber from half-lling (positive or negative, denoting electron or hole doping, respectively) in canonicalensemble, $\hat{N}$ is the electron num ber operator, and $N$ is the num ber of spatial lattioe sites in the system. $\hat{H}$ is the usual one-band H ubbard H am iltonian:

$$
\begin{equation*}
H=\int_{\text {hiji }}^{X} t_{i j}\left(c_{i}^{y} c_{j}+h: C:\right)+U_{i}^{X} n_{i^{n} n_{i \#}} \frac{U}{2}_{i}^{X} n_{i}: \tag{2}
\end{equation*}
$$

The sum $m$ ation in the hopping term $t_{i j}$ is perform ed over all nearest-neighb or pairs of the $H$ ubbard $m$ olecule. For the $\mathrm{C}_{60} \mathrm{~m}$ olecule we have set $\mathrm{t}_{\mathrm{ij}}=\mathrm{t}$ for the links betw een the pentagons and hexagons and $t_{i j}=1: 2 t$ for the links betw een hexagons. In all other cases $t_{i j}$ w as set equal to $t$ for all links, with $t$ used as an energy unit. $U$ is the on-site C oulom b repulsion (H ubbard) term, and an extra diagonalterm has been added to the H am iltonian so that $=0$ corresponds to half- lling on bipartite lattices.
Follow ing $D$ agotto et al. $[\overline{6}]$, we analytically continue Eq. ( $\overline{1}$ (1) to im aginary chem ical potential ! i, where
is real. Then the inverse Fourier transform of Eq . (1i) gives

$$
\begin{equation*}
Z_{C}(n)=\frac{Z}{2}_{2}^{Z_{0}} d e^{i(n+N)} Z_{G C}(=i): \tag{3}
\end{equation*}
$$

In AFQMC the grand canonical partition function is


FIG. 1: Fit of real (squares) and im ag̣inary (circles) parts of determ inant ratios according to Eq. (12) for a tetrahedron m olecule.
given by

$$
\begin{align*}
& Z_{G C}()=X^{Y} \operatorname{det}\left[1+B_{L}() B_{L} \quad()\right.  \tag{B}\\
& \underset{X}{f}{ }^{f}=1 \tag{4}
\end{align*}
$$

where the ferm ion degrees of freedom have been traced out, and the $B_{1} m$ atrices are de ned as

$$
\begin{align*}
& B_{1}()=e^{k} e^{V}{ }^{(1)} ;  \tag{5}\\
& (K)_{i j}=\quad \sum_{i j}^{\hbar_{j}} \text { for } i, j \text { nearest neighbors; }  \tag{6}\\
& V_{i j}(1)=i j_{i j}[1(1)+\quad]: \tag{7}
\end{align*}
$$

Here is the im aginary tim e discretization intervaland $\tanh ^{2}(=2)=\tanh (\mathrm{U}=4)$. Thus, the original problem of taking a trace over ferm ionic degrees of freedom has been replaced by a problem of tracing over auxiliary Ising variables $i(1)$, introduced at every space-tim epoint ( $\mathrm{i} ; 1$ ). Inserting Eq. (4) $)_{1}^{\prime \prime}$ into Eq. ( $\left.\overline{3}\right)$, we get

$$
\begin{align*}
& Z_{C}(n)=\sum_{f g^{2}}^{X} \bar{Z}_{2}^{2} d e^{i(n+N)} \operatorname{det} O(f g ; i) " \\
& \operatorname{det} O(f \mathrm{~g} ; \mathrm{i})_{\#} \text { : } \tag{8}
\end{align*}
$$



$$
\begin{equation*}
\frac{Z_{C}(n)}{Z_{G C}(0)}=X_{f g}^{X} P(f g ; 0) Z_{2}^{2} d^{i n}(\quad) \tag{9}
\end{equation*}
$$

where

$$
\begin{equation*}
\text { ( ) } \quad e^{i n} \frac{\operatorname{detO}(f \mathrm{~g} ; \mathrm{i}) n \operatorname{det} \mathrm{O}(\mathrm{f} g ; i)_{\#}}{\operatorname{det} \mathrm{O}(\mathrm{f} g ; 0) n \operatorname{detO}(\mathrm{f} g ; 0)_{\#}} ; \tag{10}
\end{equation*}
$$

and

$$
\begin{equation*}
P(f \mathrm{~g} ; 0)=\frac{\mathrm{d} \operatorname{detO}(\mathrm{f} g ; 0) n \operatorname{detO}(\mathrm{f} g ; 0)_{\#}}{\mathrm{fg} \operatorname{det} O(\mathrm{f} g ; 0) n \operatorname{det}(\mathrm{f} g ; 0)_{\#}} \tag{11}
\end{equation*}
$$



FIG.2: Fits of IC PQMC data for a tetrahedron molecule at low tem peratures for electron (a) and hole (b) doping. NLF form $s$ for (a) and (b) are given by Eq. (14) and Eq. (15) . ED results are also show $n$ for com parison.
is the probability distribution for $Z_{G C}(0)$. Since there is alw ays an energy gap above and below half-lling for any nite system, we expect the ferm ion determ inants to be nearly -independent at low tem peratures. Therefore, we can generate the Ising eld con gurations f $g$ for $=0$ and use these con gurations to calculate system properties at \& 0 .

Sim ilar to the expansion in Eq. $[\overline{[1]})$, we expect that the determ inant ratio ( ) in Eq. ( 10 ) com plex Fourier series in the particle num ber $n$

$$
\begin{aligned}
()= & C_{0}(f g)+X_{n=1}^{X^{N}}\left[c_{n}(f g)+c_{n}(f g)\right] \cos (n) \\
& +X_{n=1}^{X^{N}}\left[G_{n}(f g) \quad c_{n}(f g)\right] \sin (n) ; \quad(12)
\end{aligned}
$$

where $n(n)$ represents a doping of $n$ electrons (holes) w th respect to half-lling. Eq. (12 $\overline{2}_{1}$ ) is real for sys tem $s w$ ith particle-hole sym $m$ etry, singe then $c_{n}(f g)=$ $C_{n}$ (f g). W hen we substitute Eq. (12) back into Eq. $\left(\mathrm{g}_{1}\right)$, we see that $\mathrm{Z}_{\mathrm{C}}(\mathrm{n})=\mathrm{Z}_{\mathrm{G}}(0)=\mathrm{hc}_{\mathrm{n}} \mathrm{i}$, where the average h:::i is over the Ising eld con gurations $f$ g generated from the probability distribution $P(f g ; 0)$. In the case of negative weight we replace $P$ by its absolute value $P j$ and include a sign $S=P=P j$ in the average: $Z_{C}(n)=Z_{G c}(0)=h_{n} S i=h S i$. The average $h::: i$

|  |  | LF | N LF | ED (PQ M C) |
| :--- | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{4}$ | $1 ; 0$ | $0.85(1)$ | $0.87(2)$ | 0.82843 |
| $(\mathrm{U}=2 \mathrm{t})$ | $1 ; 0$ | $-0.458(9)$ | $-0.358(9)$ | -0.34949 |
|  | $2 ; 1$ | $1.9(1)$ | $2.0(1)$ | 2.0 |
|  | $2 ; 1$ | $-0.400(6)$ | $-0.397(6)$ | -0.40466 |
| $\mathrm{C}_{8}$ | $1 ; 0$ | $1.20(2)$ | $1.27(2)$ | 1.26224 |
| $(\mathrm{U}=4 \mathrm{t})$ | $2 ; 1$ | $1.44(3)$ | $1.5(2)$ | 1.27490 |
| $\mathrm{C}_{12}$ | $1 ; 0$ | $0.81(1)$ | $0.997(7)$ | 0.99596 |
| $(\mathrm{U}=2 \mathrm{t})$ | $1 ; 0$ | $0.041(1)$ | $0.10(1)$ | 0.07408 |
| $\mathrm{C}_{60}$ | $1 ; 0$ | $0.43(5)$ | $0.57(3)$ | $0.561(7)$ |
| $(\mathrm{U}=4 \mathrm{t})$ | $1 ; 0$ | $0.9(1)$ | $0.88(4)$ | $0: 86(2)$ |

TABLE I: ICPQMC results on tetrahedron ( $\mathrm{C}_{4}$ ), cube ( $\mathrm{C}_{8}$ ), truncated tetrahedron $\left(\mathrm{C}_{12}\right)$ and $\mathrm{C}_{60}$ molecules. $\mathrm{n} ; 0=$ $E(n) E(0)$ is the energy di erence betw een the ground states of the two llings. Data_m arked by are PQMC results, as described in Section IIIB,
now refers to the probability distribution $f$. As we are interested in regions near half- lling, the sign problem does not lim it the applicability of our $m$ ethod.

At low tem peratures the canonical partition function ratio will be dom inated by $n ; 0=E(n) \quad E(0)$, the energy di erence betw een the ground states for the two llings, and w ill take the form

$$
\begin{equation*}
\frac{Z_{c}(n)}{Z_{c}(0)}=\frac{h c_{n} i}{h c_{0} i}!d_{n ; 0} \quad n ; 0 \quad \text { as } \quad!1 \text {; } \tag{13}
\end{equation*}
$$

$w$ here $d_{n} ; 0=d_{n}=d_{0}$, $w$ ith $d_{n}$ being the degeneracy of the ground state at lling $\mathrm{n} . \mathrm{W}$ hen there is an energy level close to the ground state (produced by the elem entary excitations such as spin waves), we include it explicitly in the tting expressions:

$$
\begin{array}{r}
\frac{Z_{C}(n)}{Z_{C}(0)}=\frac{h c_{n} i}{h c_{0} i}!\frac{d_{n ; 0} e{ }_{n ; 0}+f_{n ; 0} e^{f_{s w}}}{1+f_{0 ; 0} e \underset{s w}{0}} \\
\text { as } \quad \frac{1}{{ }_{n ; 0}} ; \frac{1}{{ }_{s w}^{n}}: \tag{14}
\end{array}
$$

H ere $f_{n} ; 0=d_{s w}^{n}=d_{0}$, where $d_{s w}^{n}$ is the degeneracy of the spin wave state at lling $n$, and ${ }_{s w}=E_{s w}(n) \quad E(0)$ are the spin wave gaps at lling $n \mathrm{w}$ ith respect to the ground state at half- lling.

B ased on the above discussion, we form ulate the follow ing calculation procedure:

1. Generate the Ising eld con guration $f \mathrm{~g}$ according to the probability distribution $P(f g ; 0)$ in the $A F Q M C$ simulation of $Z_{G C}(0)$.
2. Evaluate the average of the determ inant ratio on the lefthand side of Eq. (12 $\underline{1}^{-1}$ ) over the Ising eld con gurations for a set of values.
3. Fit the real and in aginary parts of Eq. (12i) respectively to determ ine the average values of $h_{n} i$, $\mathrm{n}=0 ; 1 ; 2 ;:::$. From now on we will refer to these values sim ply as $C_{n}$.


F IG . 3: Fits of the real (squares) and im aginary (circles) parts ofdeterm inant ratios according to Eq. (12) for a C 60 m olecule.
4. Fit the canonical partition function ratios $Z_{C}(n)=Z_{C}(0)=c_{n}=c_{0}, n=1 ; 2$;::: w ith low temperature canonical partition function ratio expressions (13) or (14) to obtain energy gaps. Below wew ill refer to these ts as linear (LF) and non-linear ( $\mathrm{N} L F)$, respectively.

## III. A P P LIC A T IO N

IC PQMC sim ulations have been carried out on tetrahedron, cube, truncated tetrahedron and $\mathrm{C}_{60} \mathrm{~m}$ olecules. For each $m$ olecule, we have run the sim ulations at tem peratures $t=2: 0 ; 2: 5 ; \quad ; 6: 5 ; 7: 0$. The im aginary chem icalpotentiali was chosen so that $0 \ll=$, and we used a set of 20 evenly distributed values in this range. W e have num erically checked that the real part of Eq. (12) is an even function around $=0$, while the im aginary part is odd. U sing this property, we have $m$ apped out the determ inant ratio data for $>0$. For the special particle-hole sym $m$ etric case, such as a 2D square lattice, we have tested our program sfor the 22 and 44 system $s$, reproducing the results of $R$ ef. [ [ $\left[\begin{array}{l}\mathrm{\sigma}\end{array}\right]$.

## A. Tetrahedron, C ube and Truncated Tetrahedron

Fig. $\overline{1}$ displays the $t$ of the real and im aginary parts of Eq. (121') for a tetrahedron molecule ( $\mathrm{C}_{4}$ ). Sim ilar ts were perform ed for data at all tem peratures, generating a set of coe cients $c_{n}$. K now ledge of these coe cients enables us to calculate the partition function ratios at various tem peratures, and, at low tem peratures, to linearly $t$ the logarithm of these ratios to obtain the energy gaps and degeneracy ratios. R esults of th is procedure are presented in F ig. .

2; 1 from LF agree nicely $w$ th ED, while 1;0 does not. A likely cause of this discrepancy is the existence of a highly degenerate ( $d_{\mathrm{sw}}^{0}=9$ ) spin wave energy level very close ( $\left.{ }_{\text {sw }}^{0}=0: 14258 \mathrm{t}\right)$ to the ground state $\left(\mathrm{d}_{0}=2\right.$ ) at half-lling. Results of the ts for electron $(n=1)$ and
hole $\left(\mathrm{n}=1\right.$ ) doping are presented in F igs. ${ }^{2}$, ra and respectively. The NLFs were obtained using form (14') by xing the spin wave and degeneracy param eters to the values found by ED :

$$
\begin{array}{ll}
\mathrm{f}_{1 ; 0}=3 ; & \mathrm{S}_{\mathrm{SW}}=1: 18268 \mathrm{t} ;  \tag{15}\\
\mathrm{f}_{0 ; 0}=4: 5 ; & \mathrm{SW}_{\mathrm{SW}}=0: 14258 \mathrm{t}:
\end{array}
$$

In the case of hole doping the spin wave term proportional to $f_{1 ; 0}$ in the num erator of Eq. (1-4) has been neglected.

Exam ining Fig. ${ }_{2}{ }_{2}$ we nd that inclusion of spin waves does not $m$ ake a substantial di erence: LF and NLF curves are nearly overlapping [w th a slight di erence around $t=2$ for $\left.\ln \left(Z_{c}(1)=Z_{c}(0)\right)\right]$ and are very close to the exact values. This insensitivity to the tting param eters $m$ akes accurate extraction of energy gaps from partition function ratios di cult.

A nalogous sim ulations and LF /N LF ttings were perform ed for cube ( $\mathrm{C}_{8}$ ) and truncated tetrahedron ( $\mathrm{C}_{12}$ ) $m$ olecules. The energy gaps $m$ easured using this procedure are sum $m$ arized in Table $\mathbf{i}+\mathrm{t}$. The tting procedure for $\mathrm{C}_{60}$ is described below.

$$
\text { B. } \mathrm{C}_{60}
$$

Fig. Eq. (12 ) for a $\mathrm{C}_{60} \mathrm{~m}$ olecule. The im aginary parts of the determ inant ratios are positive for $>0$, which is different from the tetrahedron and truncated tetrahedron cases. The cause of this di erence is the relative size of electron and hole gaps in the system. T he larger the gaps, the sm aller the corresponding canonical partition function ratios $Z_{c}(n)=Z_{c}(0)$. For the tetrahedron and the truncated tetrahedron the electron gaps are larger than the hole gaps, so $\mathrm{C}_{1}<\mathrm{C}_{1}$. In contrast, for the $\mathrm{C}_{60}$ $m$ olecule the electron gap is sm aller than the hole gap, so $C_{1}>C_{1}$. Therefore, the relative size of the canonical partition function ratios results in a positive im aginary part of the determ inant ratios for $>0$ in $F$ ig. $\overline{\underline{k}}$ due to Eq. (12 $1^{4}$ ). Sim ilar ts were done for other temperatures, and the resulting canonicalpartition function param eters $c_{n}$ were obtained to calculate the canonical partition function ratios. Unfortunately, Eq. (141) contains too m any tting param eters to provide unique ts to the data. Therefore, we had to rely on the PQMC results (at $U=4 t$ ) for the gap values

$$
\begin{array}{ll}
1 ; 0=0: 561 \mathrm{t} ; & 0  \tag{16}\\
{ }^{1}=1: 06 \mathrm{t} \\
1
\end{array}
$$

and on the analysis of the $m$ olecular orbitalenergy level diagram ( F ig. 3 of $R$ ef. ' $\mathbf{I n}_{1}^{\prime}$ ') for the degeneracies and their ratios

$$
\begin{align*}
& d_{0}=1 ; \quad d_{1 ; 0}=6 ; \quad d_{1 ; 0}=10 ; \\
& f_{1 ; 0}=120 ; f_{1 ; 0}=10 ; f_{0 ; 0}=30: \tag{17}
\end{align*}
$$

W e were able to dem onstrate the consistency of the results obtained by the two methods (ICPQMC and


FIG.4: Fits of ICPQMC data for a $C_{60} \mathrm{~m}$ olecule at low tem peratures for electron and hole doping. e. (h.) denotes electron (hole) doping.

PQMC) by em ploying a follow ing procedure. We rst let all three gap values be free tting param eters. Fitting results are then in agreem ent w th the PQMC results, albeit $w$ ith rather large uncertainties. Then we $l l$ in the twoPQMC gap values ${ }_{\text {sw }}{ }^{1}$ and $\left.{ }_{\text {sw }}^{0} \mathbb{E q} .\left(1 \overline{1}^{-1}\right)\right]$, and let

1;0 be the only free param eter. This procedure, in general, yields the gap values consistent w the ones previously obtained using PQMC m ethod [1] [1] . D etailed results are presented in Table 告 w th representative ts show $n$ in $F$ ig. ${ }^{\prime} I^{\prime \prime}$.

## IV. CONCLUSION

We have generalized the particle-hole symmetric ICPQMC simulation of Dagotto et al. [G] to system S w thout this sym $m$ etry, such as the tetrahedron, truncated tetrahedron, and $\mathrm{C}_{60} \mathrm{~m}$ olecule. O ur simulations show that an accurate canonicalpartition function ratio can be obtained through this technique. U nfortunately, the tting of these ratios to obtain accurate energy gaps for $\mathrm{C}_{60}$ is im practical. N evertheless, consistency betw een ED , PQMC and ICPQMC has been found.

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